



74LVC2G06

DUAL INVERTERS with OPEN DRAIN OUTPUTS

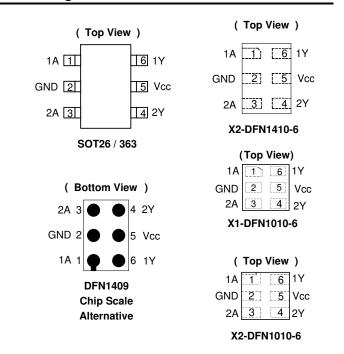
Description

The 74LVC2G06 is a dual inverter gate with open drain outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The input is tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down. The open-drain output can be connected to other open drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32mA.

Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- -24mA Output Drive at 3.0V
- CMOS Low Power Consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- DFN1409 package designed as a direct replacement for chip scale packaging.
- Range of Package Options SOT26, SOT363, X1-DFN1010-6, X2-DFN1010-6, X2-DFN1409-6, and X2-DFN1410-6
- Leadless Packages Named per JESD30E
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

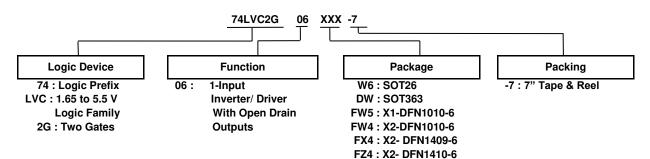
- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks, Tablets
 - Computer Peripherals, Hard Drives, SSD, CD/DVD ROM
 - TV, DVD, DVR, Set-Top Box
 - Cell Phones, Personal Navigation / GPS
 - MP3 Players, Cameras, Video Recorders

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Ordering Information



Device	Package	ackage Package Package		7" Tape and	Reel (Note 5)
Device	Code	(Note 4)	Size	Quantity	Part Number Suffix
74LVC2G06W6-7	W6	SOT26	2.8mm X 2.2 mm X 1.1mm 0.95 mm lead pitch	3,000/Tape & Reel	-7
74LVC2G06DW-7	DW	SOT363	2.0mm X 2.0mm X 1.1mm 0.65 mm lead pitch	1 3 000/Tane & Reel 1	
74LVC2G06FW5-7	FW5	X1-DFN1010-6	1.0mm X 1.0mm X 0.5mm 0.35 mm pad pitch	5,000/Tape & Reel	-7
74LVC2G06FW4-7	FW4	X2-DFN1010-6	1.0mm X 1.0mm X 0.4mm 0.35 mm pad pitch	5,000/Tape & Reel	-7
74LVC2G06FX4-7	FX4	X2-DFN1409-6 Chip Scale Alternative	1.4mm X 0.9mm X 0.4mm 0.5 mm pad pitch	5,000/Tape & Reel	-7
74LVC2G06FZ4-7	FZ4	X2-DFN1410-6	1.4mm X 1.0mm X 0.4mm 0.5 mm pad pitch	1 5 000/Tane & Reel	

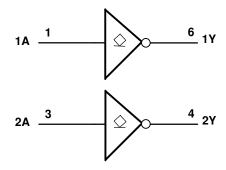
Notes: 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

5. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.

Pin Descriptions

Pin Name	Pin.	Function
1A	1	Data Input
GND	2	Ground
2A	3	Data Input
2Y	4	Data Output Open Drain
V _{CC}	5	Supply Voltage
1Y	6	Data Output Open Drain

Logic Diagram



Function Table

Inputs	Output
Α	Υ
Н	L
L	Z



Absolute Maximum Ratings (Notes 6 & 7) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +6.5	V
VI	Input Voltage Range	-0.5 to +6.5	V
V _O	Voltage Applied to Output in High Impedance or I _{OFF} State	-0.5 to +6.5	V
V _O	Voltage Applied to Output in High or Low State	-0.3 to V _{CC} +0.5	V
l _{IK}	Input Clamp Current V _I < 0	-50	mA
lok	Output Clamp Current V _O < 0	-50	mA
Io	Continuous Output Current	-50	mA
	Continuous Current Through V _{DD} or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Note

Recommended Operating Conditions (Note 8) (@T_A = +25°C, unless otherwise specified.)

Symbol		Parameter	Min	Max	Unit
V	Operating Voltage	Operating	1.65	5.5	٧
V _{CC}	Operating Voltage	Data Retention Only	1.5	_	V
		V _{CC} = 1.65V to 1.95V	0.65 X V _{CC}	_	
.,	High Lovel Input Voltage	V _{CC} = 2.3V to 2.7V	1.7	_	V
V _{IH}	High-Level Input Voltage	V _{CC} = 3V to 3.6V	2	_	V
		V _{CC} = 4.5V to 5.5V	0.7 X V _{CC}	_	
		V _{CC} = 1.65V to 1.95V	_	0.35 X V _{CC}	
	Law Law Law Waltage	V _{CC} = 2.3V to 2.7V	_	0.7	V
V_{IL}	Low-Level Input Voltage	V _{CC} = 3V to 3.6V	_	0.8	V
		V _{CC} = 4.5V to 5.5V	_	0.3 X V _{CC}	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 1.65V	_	4	
		V _{CC} = 2.3V	_	8	
l _{OL}	Low-Level Output Current		_	16	mA
		V _{CC} = 3V	_	24	
		V _{CC} = 4.5V	_	32	
		$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$	_	20	
Δt/ΔV	Input Transition Rise or Fall Rate		_	10	ns/V
		$V_{CC} = 5V \pm 0.5V$	_	10	
TA	Operating Free-Air Temperature		-40	+125	°C

Note: 8. Unused inputs should be held at V_{CC} or Ground.

Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



Electrical Characteristics

Comple of	Downwater	Took Conditions	V	-40°C to	+85°C	-40°C to	+125°C	
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit
		$I_{OL} = 100 \mu A$	1.65V to 5.5V	_	0.1	_	0.1	
		$I_{OL} = 4mA$	1.65V	_	0.45	_	0.70	
	Low-Level Output	$I_{OL} = 8mA$	2.3V	_	0.3	_	0.45	v
V _{OL}	Voltage	I _{OL} = 16mA	3V	_	0.4	_	0.60	V
		I _{OL} = 24mA	3 V	_	0.55	_	0.80	
		I _{OL} = 32mA	4.5V	_	0.55	_	0.80	
l _l	Input Current	V _I = 5.5V or GND	0 to 5.5V	_	± 5	_	± 20	μΑ
loz	Z State Leakage Current	V _O = 0 to 5.5V	3.6V	_	± 10	_	± 10	μA
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 5.5V$	0V	_	± 10	_	± 20	μA
Icc	Supply Current	$V_I = 5.5V$ or GND, $I_O = 0$	1.65V to 5.5V	_	10		40	μΑ
ΔI _{CC}	Additional Supply Current	Input at V _{CC} -0.6V	3V to 5.5V	_	500	_	5000	μA

Package Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C.)

Symbol	Parameter	Package	Conditions	Min	Тур	Max	Unit
Cı	Input Capacitance	Typical of All Packages	Vcc = 3.3V $V_1 = V_{CC}$ or GND		3.5	_	pF
		SOT26		_	204	_	
		SOT363		_	371	_	
	Thermal Decistores Investiga to Ambient	X2-DFN1410-6	(Note O)	_	430		°C ///
θ_{JA}	Thermal Resistance Junction-to-Ambient	X2-DFN1409-6	(Note 9)	_	450	_	°C/W
		X1-DFN1010-6		_	495	_	1
		X2-DFN1010-6		_	510	_	
		SOT26		_	52	_	
		SOT363		_	143	_	
0	The word Decistors of Lunction to Cook	X2-DFN1410-6	(Nata 0)	_	190	_	00.00
θЈС	Thermal Resistance Junction-to-Case	X2-DFN1409-6	(Note 9)	_	225	_	°C/W
		X1-DFN1010-6		_	245	_	
		X2-DFN1010-6		_	250		

Note: 9. Test condition for all packages: Device mounted on FR-4 substrate PC board, 2oz copper with minimum recommended pad layout.

Switching Characteristics

 $T_A = -40$ °C to +85°C, $C_L = 30$ or 50pF (See Figure 1)

Parameter	From (Input)	TO (OUTPUT)		= 1.8V .15V		= 2.5V).2V	V _{CC} = ± 0	: 3.3V).3V		= 5V).5V	Unit
	(mput)	(0011 01)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Α	Y	0.5	6.5	0.5	3.9	0.5	3.4	0.5	2.9	ns

 $T_A = -40$ °C to +125°C, $C_L = 30$ or 50pF (See Figure 1)

Parameter	From (Input)	TO (OUTPUT)		: 1.8V .15V		: 2.5V).2V		= 3.3V).3V		= 5V .5V	Unit
	(mput)	(0011-01)	Min	Max	Min	Max	Min	Max	Min	Max	1
t _{pd}	Α	Υ	0.5	8.2	0.5	4.9	0.5	4.3	0.5	3.7	ns

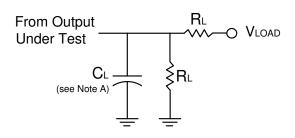


Operating Characteristics

-	±25°	\sim

	Parameter	Test Conditions	V _{CC} = 1.8V Typ	V _{CC} = 2.5V Typ	V _{CC} = 3.3V Typ	V _{CC} = 5V Typ	Unit
$C_{\sf pd}$	Power Dissipation Capacitance	f = 10 MHz	3	3	4	6	pF

Parameter Measurement Information



TEST	Condition
t _{PLZ} (See Notes D and E)	Vload
t _{PZL} (See Notes D and F)	Vload

V	Inputs			V	•	_	V/4
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R_L	V Δ
1.8V±0.15V	Vcc	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	1kΩ	0.15V
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5 V	6 V	50pF	500Ω	0.3V
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	2 X V _{CC}	50pF	500Ω	0.3V

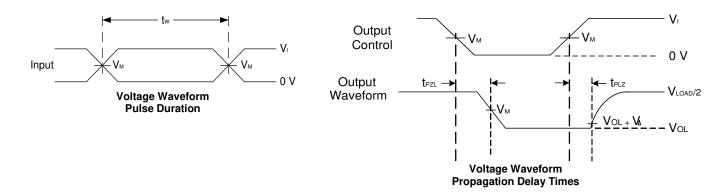


Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the open drain device t_{PLZ} and t_{PZL} are the same as $t_{\text{PD}}.$
- E. t_{PZL} is measured at V_{M} .
- F. t_{PLZ} is measured at V_{OL} + V_{Δ} .



Marking Information

(1) SOT26, SOT363

5 6 4 XX Y W X

2

XX: Identification code

Y: Year 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

52 and 53 week

X: A~Z: Internal Code

Part Number	Package	Identification Code
74LVC2G06W6-7	SOT26	Z3
74LVC2G06DW-7	SOT363	Z3

(2) X1-DFN1010-6, X2-DFN1010-6, X2-DFN1409-6, X2-DFN1410-6

(Top View)

3

XX: Identification Code

Ÿ:Year:0~9

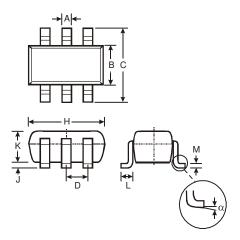
<u>₩</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week X: A~Z: Internal code

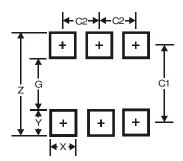
Part Number	Package	Identification Code
74LVC2G06FW4-7	X2-DFN1010-6	Z3
74LVC2G06FW5-7	X1-DFN1010-6	W3
74LVC2G06FX4-7	X2-DFN1409-6	X3
74LVC2G06FZ4-7	X2-DFN1410-6	Z3



SOT26 Package Outline Dimensions and Suggested Pad Layout



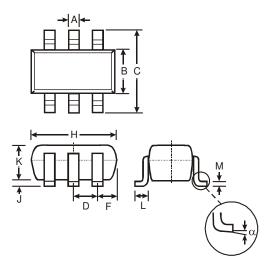
	SOT26			
Dim	Min	Max	Тур	
Α	0.35	0.50	0.38	
В	1.50	1.70	1.60	
С	2.70	3.00	2.80	
D			0.95	
Н	2.90	3.10	3.00	
J	0.013	0.10	0.05	
K	1.00	1.30	1.10	
L	0.35	0.55	0.40	
М	0.10	0.20	0.15	
α	0°	8°	_	
All Dimensions in mm				



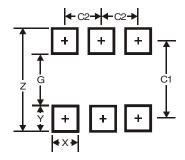
Dimensions	Value (in mm)	
Z	3.20	
G	1.60	
X	0.55	
Υ	0.80	
C1	2.40	
C2	0.95	



SOT363 Package Outline Dimensions and Suggested Pad Layout



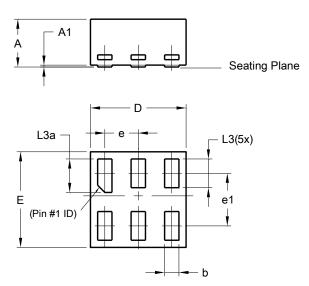
	SOT363			
Dim	Min	Max	Тур	
Α	0.10	0.30	0.25	
В	1.15	1.35	1.30	
С	2.00	2.20	2.10	
D	0.65 Typ			
F	0.40	0.45	0.425	
Н	1.80	2.20	2.15	
J	0	0.10	0.05	
K	0.90	1.00	1.00	
L	0.25	0.40	0.30	
М	0.10	0.22	0.11	
α	0°	8°	-	
All Dimensions in mm				



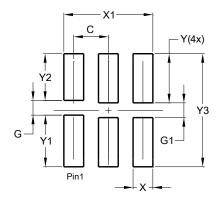
Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Υ	0.6
C1	1.9
C2	0.65



X1-DFN1010-6 (Type B) Package Outline Dimensions and Suggested Pad Layout



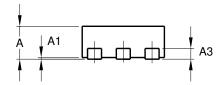
X1-DFN1010-6				
	(Ty	pe B)		
Dim	Min	Max	Тур	
Α	-	0.50	0.39	
A 1	-	0.04	-	
b	0.12	0.20	0.15	
D	0.95	1.050	1.00	
Е	0.95	1.050	1.00	
е	0.35 BSC			
e1		0.55 B	SC	
L3	0.27	0.30	0.30	
L3a	0.32	0.40	0.35	
All	All Dimensions in mm			

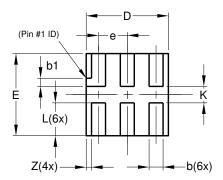


Dimensions	Value (in mm)
C	0.350
G	0.150
G1	0.150
Х	0.200
X1	0.900
Υ	0.500
Y1	0.525
Y2	0.475
Y3	1.150

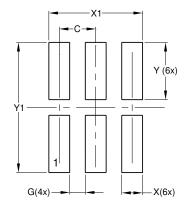


X2-DFN1010-6 Package Outline Dimensions and Suggested Pad Layout





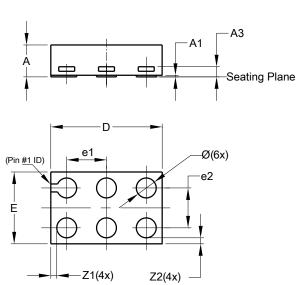
	X2-DFN1010-6			
Dim	Min	Max	Тур	
Α		0.40	0.39	
A1	0.00	0.05	0.02	
A3			0.13	
b	0.14	0.20	0.17	
b1	0.05	0.15	0.10	
D	0.95	1.05	1.00	
Е	0.95	1.05	1.00	
е	_	_	0.35	
L	0.35	0.45	0.40	
K	0.15			
Z			0.065	
All	All Dimensions in mm			



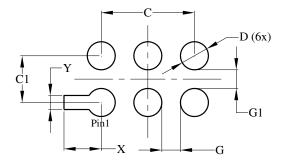
Dimensions	Value (in mm)	
С	0.350	
G	0.150	
Х	0.200	
X1	0.900	
Y	0.550	
Y1	1.250	



X2-DFN1409-6 Package Outline Dimensions and Suggested Pad Layout



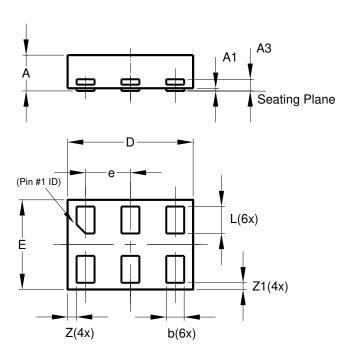
)	X2-DFN1409-6			
Dim	Min	Max	Тур	
Α	_	0.40	0.39	
A 1	0	0.05	0.02	
А3	_	_	0.13	
Ø	0.20	0.30	0.25	
D	1.35	1.45	1.40	
Е	0.85	0.95	0.90	
e1	_	-	0.50	
e2	_	l	0.50	
Z 1	_		0.075	
Z2	_		0.075	
All Dimensions in mm				



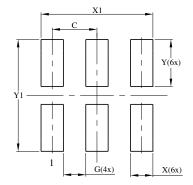
Dimensions	Value (in mm)		
С	1.000		
C1	0.500		
D	0.300		
G	0.200		
G1	0.200		
Х	0.400		
Υ	0.150		



X2-DFN1410-6 Package Outline Dimensions and Suggested Pad Layout



X2-DFN1410-6			
Dim	Min	Max	Тур
Α	_	0.40	0.39
A1	0.00	0.05	0.02
A3	_		0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
E	0.95	1.05	1.00
е			0.50
L	0.25	0.35	0.30
Z			0.10
Z 1	0.045	0.105	0.075
All Dimensions in mm			



Dimensions	Value (in mm)
С	0.500
G	0.250
Х	0.250
X1	1.250
Υ	0.525
Y1	1.250



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